## MPS2907A Series

## General Purpose Transistors

PNP Silicon

## Features

- These are $\mathrm{Pb}-$ Free Devices*


## MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Collector-Emitter Voltage | $\mathrm{V}_{\mathrm{CEO}}$ | -60 | Vdc |
| Collector-Base Voltage | $\mathrm{V}_{\mathrm{CBO}}$ | -60 | Vdc |
| Emitter - Base Voltage | $\mathrm{V}_{\text {EBO }}$ | -5.0 | Vdc |
| Collector Current - Continuous | $\mathrm{I}_{\mathrm{C}}$ | -600 | mAdc |
| Total Device Dissipation @ $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{D}}$ | 625 | mW |
| Derate above 25 $5^{\circ} \mathrm{C}$ |  | 5.0 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| Total Device Dissipation @ $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{D}}$ | 1.5 | W |
| Derate above 25 $5^{\circ} \mathrm{C}$ |  |  |  |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
| :--- | :---: | :---: | :---: |
| Thermal Resistance, Junction-to-Ambient | $\mathrm{R}_{\theta \mathrm{JA}}$ | 200 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance, Junction-to-Case | $\mathrm{R}_{\theta \mathrm{JC}}$ | 83.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## DEVICE MARKING

| Device | Line 1 | Line 2 |
| :--- | :---: | :---: |
| MPS2907AG | MPS | 2907 A |
| MPS2907ARLG | MPS2 | 907 A |
| MPS2907ARLRAG | MPS | 2907 |
| MPS2907ARLRPG | MPS | 2907 |

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ORDERING INFORMATION
See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.


[^0]ELECTRICAL CHARACTERISTICS $\left(T_{A}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS |  |  |  |  |
| Collector-Emitter Breakdown Voltage (Note 1) ( $\mathrm{I}_{\mathrm{C}}=-10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=0$ ) | $\mathrm{V}_{\text {(BR) }}$ CEO | -60 | - | Vdc |
| Collector-Base Breakdown Voltage ( $\mathrm{I}_{\mathrm{C}}=-10 \mu \mathrm{Adc}, \mathrm{I}_{\mathrm{E}}=0$ ) | $\mathrm{V}_{\text {(BR) } \mathrm{CbO}}$ | -60 | - | Vdc |
| Emitter-Base Breakdown Voltage ( $\mathrm{I}_{\mathrm{E}}=-10 \mu \mathrm{Adc}, \mathrm{I}_{\mathrm{C}}=0$ ) | $\mathrm{V}_{\text {(BR) }{ }^{\text {ebo }} \text { ( }}$ | -5.0 | - | Vdc |
| Collector Cutoff Current ( $\mathrm{V}_{\mathrm{CE}}=-30 \mathrm{Vdc}, \mathrm{V}_{\mathrm{EB} \text { (off) }}=-0.5 \mathrm{Vdc}$ ) | ICEX | - | -50 | nAdc |
| $\begin{aligned} & \text { Collector Cutoff Current } \\ & \quad\left(V_{C B}=-50 \mathrm{Vdc}, I_{E}=0\right) \\ & \left(V_{C B}=-50 \mathrm{Vdc}, I_{E}=0, T_{A}=150^{\circ} \mathrm{C}\right) \end{aligned}$ | $\mathrm{I}_{\text {cbo }}$ | - | $\begin{gathered} -0.01 \\ -10 \end{gathered}$ | $\mu \mathrm{Adc}$ |
| Base Current ( $\left.\mathrm{V}_{\mathrm{CE}}=-30 \mathrm{Vdc}, \mathrm{V}_{\mathrm{EB} \text { (off) }}=-0.5 \mathrm{Vdc}\right)$ | $\mathrm{I}_{\mathrm{B}}$ | - | -50 | nAdc |

## ON CHARACTERISTICS

| $\begin{aligned} & \text { DC Current Gain } \\ & \left(\mathrm{I}_{\mathrm{C}}=-0.1 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=-10 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=-1.0 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=-10 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=-10 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=-10 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=-150 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=-10 \mathrm{Vdc}\right)(\text { Note 1) } \\ & \left(\mathrm{I}_{\mathrm{C}}=-500 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=-10 \mathrm{Vdc}\right)(\text { Note 1) } \end{aligned}$ | $\mathrm{h}_{\text {FE }}$ | $\begin{aligned} & 75 \\ & 100 \\ & 100 \\ & 100 \\ & 50 \end{aligned}$ | $\begin{gathered} - \\ - \\ - \\ 300 \end{gathered}$ |  |
| :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { Collector-Emitter Saturation Voltage (Note 1) } \\ & \left(I_{C}=-150 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=-15 \mathrm{mAdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=-500 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=-50 \mathrm{mAdc}\right) \end{aligned}$ | $\mathrm{V}_{\mathrm{CE} \text { (sat) }}$ |  | $\begin{aligned} & -0.4 \\ & -1.6 \end{aligned}$ | Vdc |
| Base-Emitter Saturation Voltage (Note 1) $\left(I_{C}=-150 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=-15 \mathrm{mAdc}\right)$ ( $\mathrm{IC}_{\mathrm{C}}=-500 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=-50 \mathrm{mAdc}$ ) | $V_{\text {BE (sat) }}$ | - | $\begin{aligned} & -1.3 \\ & -2.6 \end{aligned}$ | Vdc |

SMALL-SIGNAL CHARACTERISTICS

| Current-Gain - Bandwidth Product (Notes 1 and 2), <br> $\left(\mathrm{I}_{\mathrm{C}}=-50\right.$ mAdc, $\left.\mathrm{V}_{\mathrm{CE}}=-20 \mathrm{Vdc}, \mathrm{f}=100 \mathrm{MHz}\right)$ | $\mathrm{f}_{\mathrm{T}}$ | 200 | - | MHz |
| :--- | :---: | :---: | :---: | :---: |
| Output Capacitance $\left(\mathrm{V}_{\mathrm{CB}}=-10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{f}=1.0 \mathrm{MHz}\right)$ | $\mathrm{C}_{\text {obo }}$ | - | 8.0 | pF |
| Input Capacitance $\left(\mathrm{V}_{\mathrm{EB}}=-2.0 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=0, \mathrm{f}=1.0 \mathrm{MHz}\right)$ | $\mathrm{C}_{\mathrm{ibo}}$ | - | 30 | pF |

## SWITCHING CHARACTERISTICS

| Turn-On Time | $\left(\mathrm{V}_{\mathrm{CC}}=-30 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=-150 \mathrm{mAdc}\right.$, $\mathrm{I}_{\mathrm{B} 1}=-15 \mathrm{mAdc}$ ) (Figures 1 and 5) | $\mathrm{t}_{\text {on }}$ | - | 45 | ns |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Delay Time |  | $\mathrm{t}_{\mathrm{d}}$ | - | 10 | ns |
| Rise Time |  | $\mathrm{tr}_{\mathrm{r}}$ | - | 40 | ns |
| Turn-Off Time | $\begin{gathered} \left(\mathrm{V}_{\mathrm{CC}}=-6.0 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=-150 \mathrm{mAdc},\right. \\ \left.\mathrm{I}_{\mathrm{B} 1}=\mathrm{I}_{\mathrm{B} 2}=15 \mathrm{mAdc}\right)(\text { Figure 2 }) \end{gathered}$ | $\mathrm{t}_{\text {off }}$ | - | 100 | ns |
| Storage Time |  | $\mathrm{t}_{\text {s }}$ | - | 80 | ns |
| Fall Time |  | $\mathrm{t}_{\mathrm{f}}$ | - | 30 | ns |

1. Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$, Duty Cycle $\leq 2 \%$.
2. $\mathrm{f}_{\mathrm{T}}$ is defined as the frequency at which $\left|\mathrm{h}_{\mathrm{fe}}\right|$ extrapolates to unity.

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Figure 1. Delay and Rise Time Test Circuit


Figure 2. Storage and Fall Time Test Circuit

TYPICAL CHARACTERISTICS


Figure 3. DC Current Gain


Figure 4. Collector Saturation Region

## MPS2907A Series

ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :--- | :---: | :---: |
| MPS2907AG | TO-92 <br> $($ Pb-Free $)$ | 5000 Units / Bulk |
| MPS2907ARLG | TO-92 <br> $($ Pb-Free $)$ | $2000 /$ Tape \& Reel |
| MPS2907ARLRAG | TO-92 <br> (Pb-Free) | TO-92 <br> (Pb-Free) |
| MPS2907ARLRPG | $2000 /$ Ammo Pack |  |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.


Figure 5. Turn-On Time


Figure 6. Turn-Off Time

## MPS2907A Series

## TYPICAL SMALL-SIGNAL CHARACTERISTICS <br> NOISE FIGURE

$\mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$


Figure 7. Frequency Effects


Figure 9. Capacitances


Figure 8. Source Resistance Effects


Figure 10. Current-Gain - Bandwidth Product

Figure 11. Collector-Emitter Saturation
Voltage vs. Collector Current


Figure 12. Base-Emitter Turn-ON Voltage vs. Collector Current

## MPS2907A Series



Figure 13. Base Emitter Saturation Voltage vs. Collector Current


STRAIGHT LEAD


BENT LEAD


STRAIGHT LEAD


BENT LEAD


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES
3. CONTOUR OF PACKAGE BEYOND DIMENSION RIS CONTOUR OF PACKA
4. DIMENSION F APPLIES BETWEEN DIMENSIONS $P$ AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD
DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIIUM.

|  | INCHES |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
|  | 0.175 | 0.205 | 4.44 | 5.21 |
| B | 0.290 | 0.310 | 7.37 | 7.87 |
| C | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.018 | 0.021 | 0.46 | 0.53 |
| F | 0.016 | 0.019 | 0.41 | 0.48 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| H | 0.095 | 0.05 | 2.42 | 2.66 |
| J | 0.018 | 0.024 | 0.46 | 0.61 |
| K | 0.500 | --- | 12.70 | --- |
| L | 0.250 | --- | 6.35 | --- |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | --- | 0.100 | -- | 2.54 |
| R | 0.135 | --- | 3.43 | --- |
| V | 0.135 | --- | 3.43 | --- |

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION FAPPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

| DIM | INCHES |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
| A | 0.175 | 0.205 | 4.44 | 5.21 |
| B | 0.290 | 0.310 | 7.37 | 7.87 |
| C | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.018 | 0.021 | 0.46 | 0.53 |
| G | 0.094 | 0.102 | 2.40 | 2.80 |
| J | 0.018 | 0.024 | 0.46 | 0.61 |
| K | 0.500 | --- | 12.70 | --- |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | --- | 0.100 | --- | 2.54 |
| R | 0.135 | --- | 3.43 | --- |
| V | 0.135 | --- | 3.43 | --- |

STYLES ON PAGE 2

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[^1]
## TO-92 (TO-226) 1 WATT

CASE 29-10 ISSUE A

| STYLE 1: |  |
| ---: | :--- |
| PIN 1. | EMITTER |
| 2. | BASE |
| 3. | COLLECTOR |
| STYLE 6: |  |
| PIN 1. | GATE |
| 2. | SOURCE \& SUBSTRATE |
| 3. | DRAIN |
| STYLE 11: |  |
| PIN 1. | ANODE |
| 2. | CATHODE \& ANODE |
| 3. | CATHODE |
| STYLE 16: |  |
| PIN 1. | ANODE |
| 2. | GATE |
| 3. | CATHODE |
| STYLE 21: |  |
| PIN 1. | COLLECTOR |
| 2. | EMITTER |
| 3. | BASE |
| STYLE 26: |  |
| PIN 1. | VCC |
| 2. | GROUND 2 |
| 3. | OUTPUT |
| STYLE 31: |  |
| PIN 1. | GATE |
| 2. | DRAIN |
| 3. | SOURCE |


| STYLE 2: |  |
| ---: | :--- |
| PIN 1. | BASE |
| 2. | EMITTER |
| 3. | COLLECTOR |
| STYLE 7: |  |
| PIN 1. | SOURCE |
| 2. | DRAIN |
| 3. | GATE |
| STYLE 12: |  |
| PIN 1. | MAIN TERMINAL 1 |
| 2. | GATE |
| 3. | MAIN TERMINAL 2 |
| STYLE 17: |  |
| PIN 1. | COLLECTOR |
| 2. | BASE |
| 3. | EMITTER |
| STYLE 22: |  |
| PIN 1. | SOURCE |
| 2. | GATE |
| 3. | DRAIN |
| STYLE 27: |  |
| PIN 1. | MT |
| 2. | SUBSTRATE |
| 3. | MT |
| STYLE $32:$ |  |
| PIN 1. | BASE |
| 2. | COLLECTOR |
| 3. | EMITTER |


| STYLE 3: |  |
| ---: | :--- |
| PIN 1. | ANODE |
| 2. | ANODE |
| 3. | CATHODE |
| STYLE 8: |  |
| PIN 1. | DRAIN |
| 2. | GATE |
| 3. | SOURCE \& SUBSTRATE |
| STYLE 13: |  |
| PIN 1. | ANODE 1 |
| 2. | GATE |
| 3. | CATHODE 2 |
| STYLE 18: |  |
| PIN 1. | ANODE |
| 2. | CATHODE |
| 3. | NOT CONNECTED |
| STYLE 23: |  |
| PIN 1. | GATE |
| 2. | SOURCE |
| 3. | DRAIN |
| STYLE 28: |  |
| PIN 1. | CATHODE |
| 2. | ANODE |
| 3. | GATE |
| STYLE 33: |  |
| PIN 1. | RETURN |
| 2. | INPUT |
| 3. | OUTPUT |


| STYLE 4: PIN 1. | CATHODE | STYLE 5: PIN 1. | DRAIN |
| :---: | :---: | :---: | :---: |
| 2. | CATHODE | 2. | SOURCE |
| 3. | ANODE | 3. | GATE |
| STYLE 9: |  | STYLE 10: |  |
| PIN 1. | BASE 1 | PIN 1. | CATHODE |
| 2. | EMITTER | 2. | GATE |
| 3. | BASE 2 | 3. | ANODE |
| STYLE 14: |  | STYLE 15: |  |
| PIN 1. | EMITTER | PIN 1. | ANODE 1 |
| 2. | COLLECTOR | 2. | CATHODE |
| 3. | BASE | 3. | ANODE 2 |
| STYLE 19: |  | STYLE 20: |  |
| PIN 1. | GATE | PIN 1. | NOT CONNECTED |
| 2. | ANODE | 2. | CATHODE |
| 3. | CATHODE | 3. | ANODE |
| STYLE 24: |  | STYLE 25: |  |
| PIN 1. | EMITTER | PIN 1. | MT 1 |
| 2. | COLLECTOR/ANODE | 2. | GATE |
| 3. | CATHODE | 3. | MT 2 |
| STYLE 29: |  | STYLE 30: |  |
| PIN 1. | NOT CONNECTED | PIN 1. | DRAIN |
| 2. | ANODE | 2. | GATE |
| 3. | CATHODE | 3. | SOURCE |
| STYLE 34: |  | STYLE 35: |  |
| PIN 1. | INPUT | PIN 1. | GATE |
| 2. | GROUND | 2. | COLLECTOR |
| 3. | LOGIC | 3. | EMITTER |


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